

Improving solar radiation absorbance of high refractory ceramics by fs Ti:sapphire laser surface treatment

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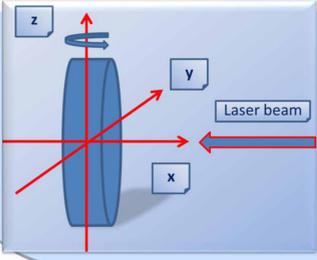
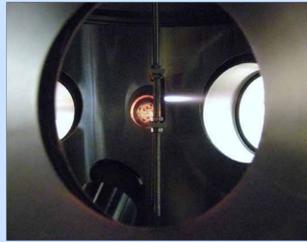
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E-MRS 2013
SPRING MEETING
Technical sessions: May 27 -31
Congress Center
Strasbourg, France

fs Ti:sapphire laser treatment

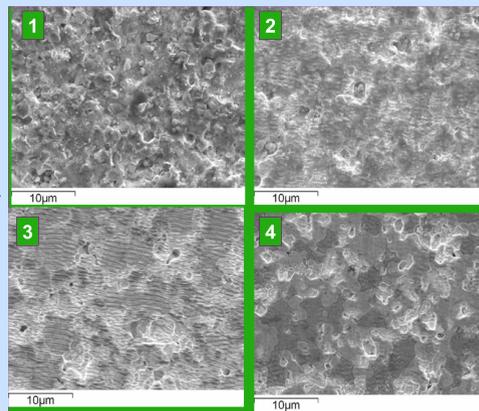
- Ultra -short Ti:Sapphire pulsed laser source, (Spectra Physics Spitfire Pro XP, 800 nm, 2.7 mJ, 100 fs) operating at
- 800 nm, repetition rate 1000 Hz.
- The beam was perpendicular to the ceramic sample surface
- Focused by a plano -convex lens, focal distance of 300mm.
- An x,y,z translation stage (computer controlled) was employed to obtain a pattern of parallel lines, over square or circular areas.
- All treatments has been carried out in vacuum (10^{-6} ÷ 10^{-7} mbar)



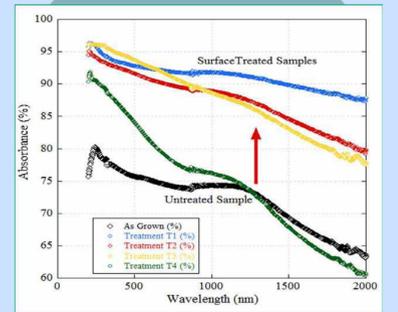
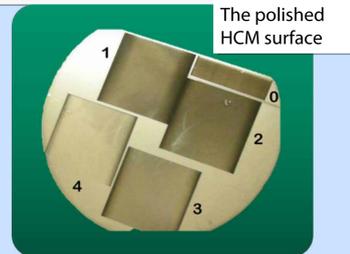
The vacuum chamber with the translation stage (x,y,z)

The square areas with different laser treatments

The different surface laser treatments: preliminary experiments

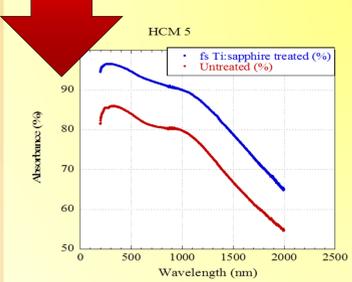
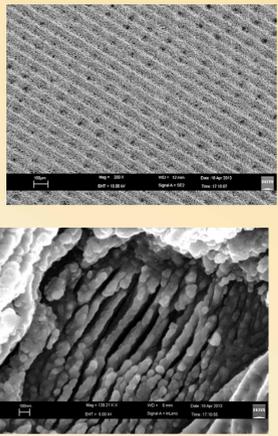


low-resolution SEM images of the corresponding treated areas



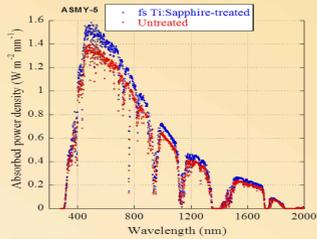
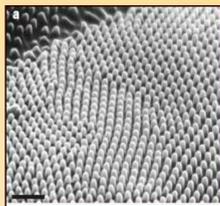
Light absorbance

The fs-laser patterned surface of HCM absorber

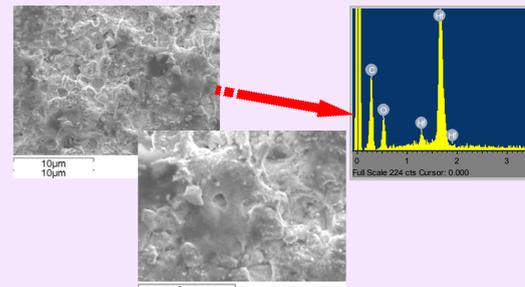


Increased solar radiation absorbance

The mott eye effect



Details of track 1



SEM -EDS analysis

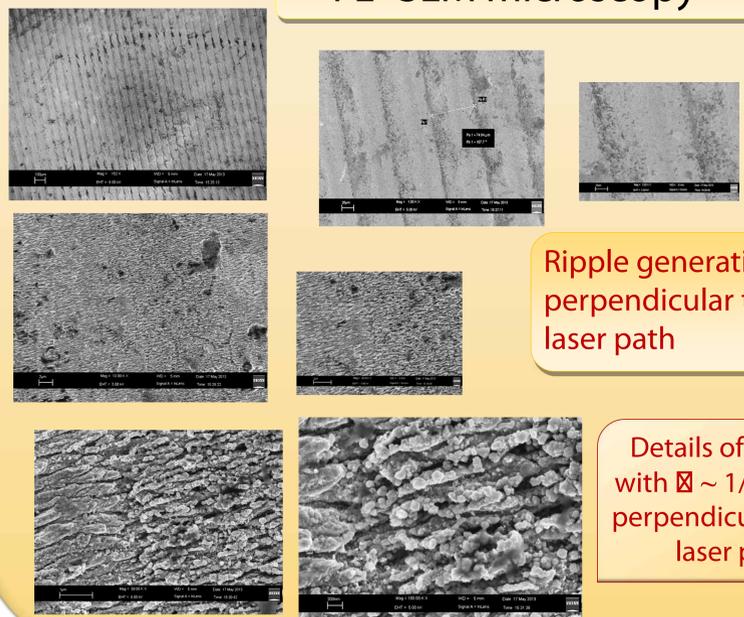
Oxygen enrichment after the laser treatment, but no well -defined pattern, rather a process of surface damage and roughening due to effects of ablation / redeposition.

From the fs-laser treated HCM (HfC + MoSi₂) sintered ceramic absorber to the Vacuum Encapsulated Conversion Modulus installed at the Solar Test Platform



d = 30 mm

FE -SEM microscopy



Ripple generation perpendicular to the laser path

Details of ripples with $\lambda \sim 1/4$ and $1/8$ perpendicular to the laser path

Acknowledgements

This poster draws on work undertaken as part of the project CLaN (Combined Laser Nanotechnology) co-financed by the Operational Programme ERDF Basilicata 2007-2013.